

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
-30V	25mΩ @ V _{GS} = -10V	-8.5A
	38mΩ @ V _{GS} = -4.5V	-6.9A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

- DC-DC converters
- Power-management functions
- Load switches

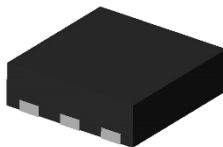
Features

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact_us) or your local Diodes representative.**
<https://www.diodes.com/quality/product-definitions/>

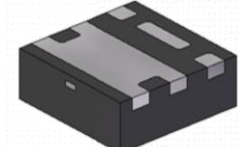
Mechanical Data

- Package: U-DFN2020-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.0065 grams (Approximate)

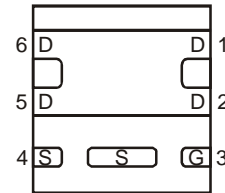
U-DFN2020-6 (Type E)



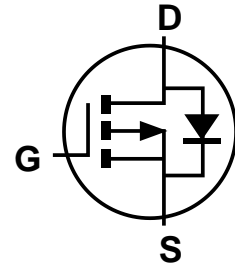
Top View



Bottom View



Pin Out
Bottom View



Internal Schematic

Ordering Information (Note 4)

Part Number	Marking	Package	Packing	
			Qty.	Carrier
DMP3027LFDE-7	F7	U-DFN2020-6 (Type E)	3,000	Tape & Reel
DMP3027LFDE-13	F7	U-DFN2020-6 (Type E)	10,000	Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



F7 = Product Type Marking Code
 YWX = Date Code Marking
 Y = Year (ex: 3 = 2023)
 W = Week (ex: a = Week 27; z Represents Week 52 and 53)
 X = Internal Code (ex: U = Monday)

Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	3	4	5	6	7	8	9	0	1	2	3	4

Week	1-26	27-52	53
Code	A-Z	a-z	z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	T	U	V	W	X	Y	Z

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 5) V _{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	I _D	-8.5 -6.8	A
Maximum Body Diode Forward Current (Note 5)			I _S	-2.8	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-45	A
Avalanche Current (Note 6) L = 0.1mH			I _{AS}	25	A
Avalanche Energy (Note 6) L = 0.1mH			E _{AS}	31	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Total Power Dissipation (Note 7)			P _D	1.0	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State		R _{θJA}	113.8	°C/W
Total Power Dissipation (Note 5)			P _D	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State		R _{θJA}	45.7	°C/W
Thermal Resistance, Junction to Case (Note 5)			R _{θJC}	6.2	
Operating and Storage Temperature Range			T _J , T _{STG}	-55 to +150	°C

- Notes:
- Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 - I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 - Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	V _{GS} = 0V, I _D = -250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	V _{DS} = -30V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±20V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	-1.2	—	-2.4	V	V _{DS} = V _{GS} , I _D = -250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	18.3	25	mΩ	V _{GS} = -10V, I _D = -7A
		—	33.6	38		V _{GS} = -4.5V, I _D = -6.2A
Diode Forward Voltage	V _{SD}	—	-0.7	-1.2	V	V _{GS} = 0V, I _S = -2.1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	—	1142	—	pF	V _{DS} = -15V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	145	—		
Reverse Transfer Capacitance	C _{rss}	—	116	—		
Gate Resistance	R _G	—	4.8	—	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz
Total Gate Charge (V _{GS} = -10V)	Q _g	—	21.8	—	nC	V _{DS} = -15V, I _D = -7A
Total Gate Charge (V _{GS} = -4.5V)	Q _g	—	11.2	—		
Gate-Source Charge	Q _{gs}	—	3.3	—		
Gate-Drain Charge	Q _{gd}	—	4.6	—		
Turn-On Delay Time	t _{D(on)}	—	5.3	—	ns	V _{GS} = -10V, V _{DD} = -15V, R _{GEN} = 6Ω I _D = -7A
Turn-On Rise Time	t _r	—	27.9	—		
Turn-Off Delay Time	t _{D(off)}	—	41.17	—		
Turn-Off Fall Time	t _f	—	30.9	—		

Notes: 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.

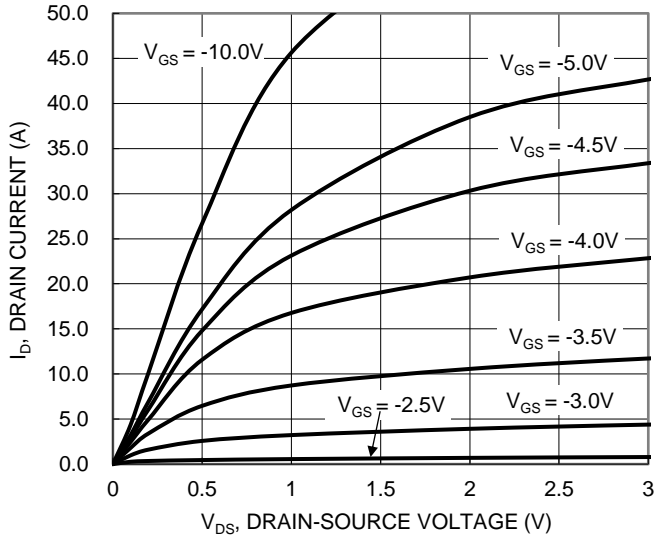


Figure 1. Typical Output Characteristic

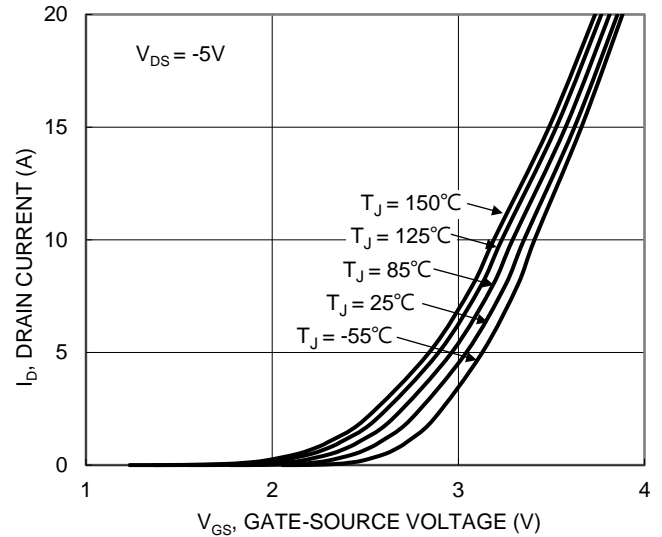


Figure 2. Typical Transfer Characteristic

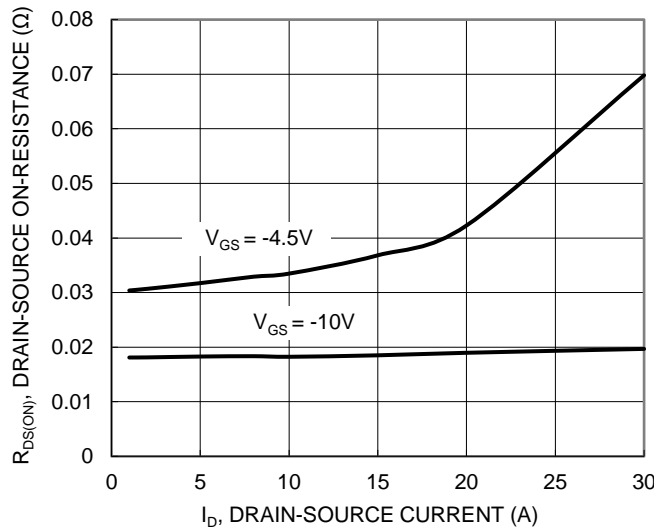


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

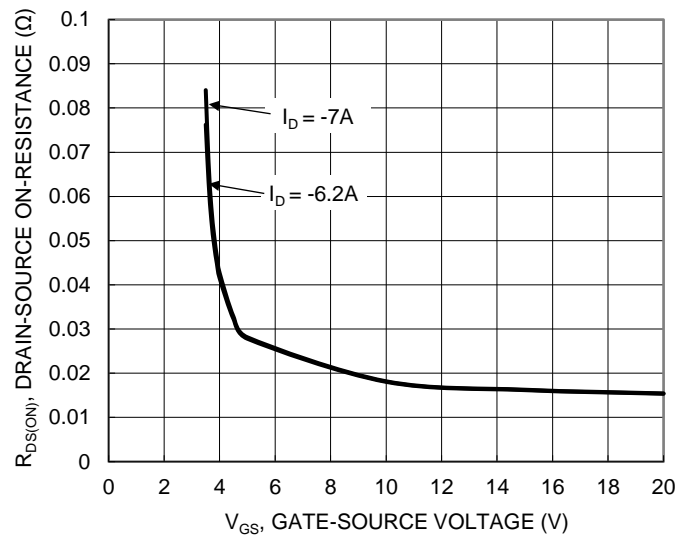


Figure 4. Typical Transfer Characteristic

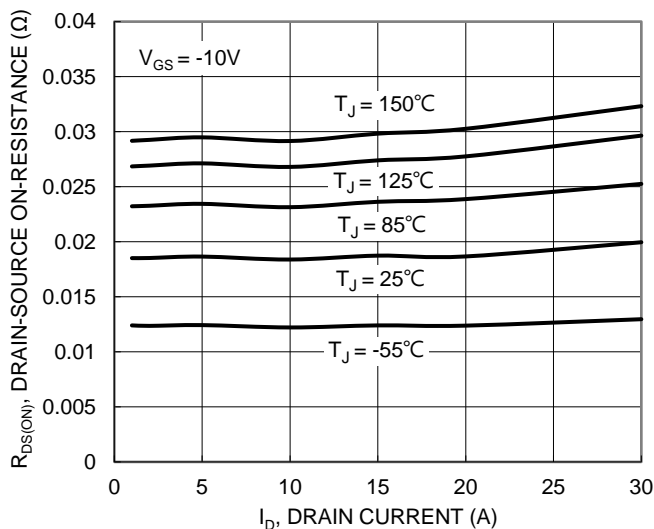


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

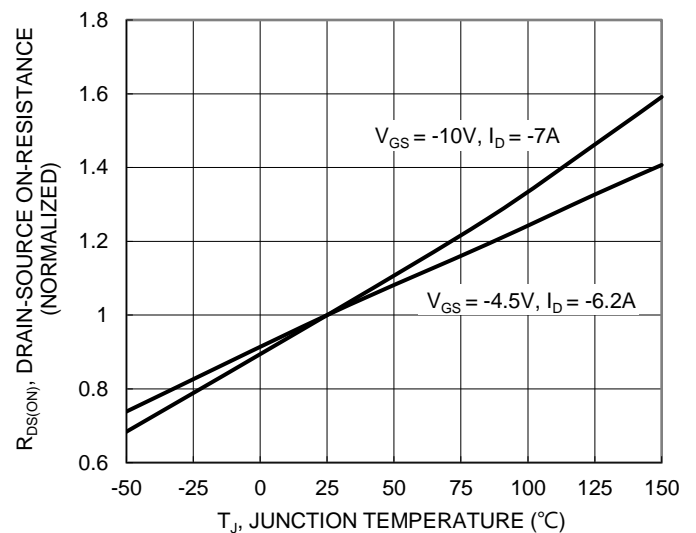


Figure 6. On-Resistance Variation with Junction Temperature

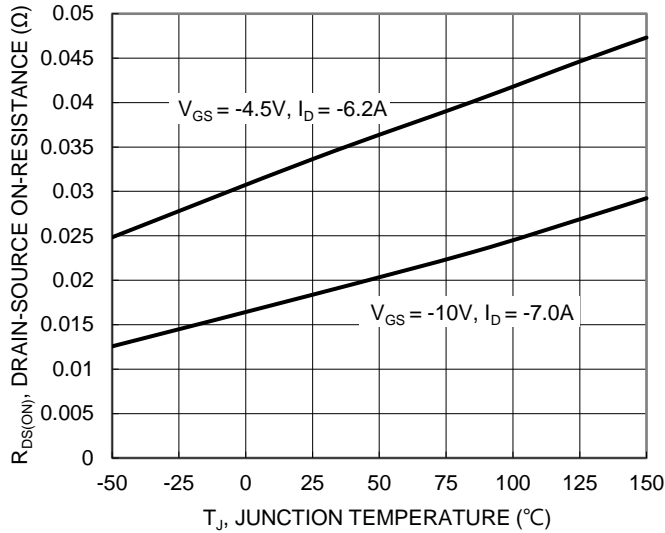


Figure 7. On-Resistance Variation with Junction Temperature

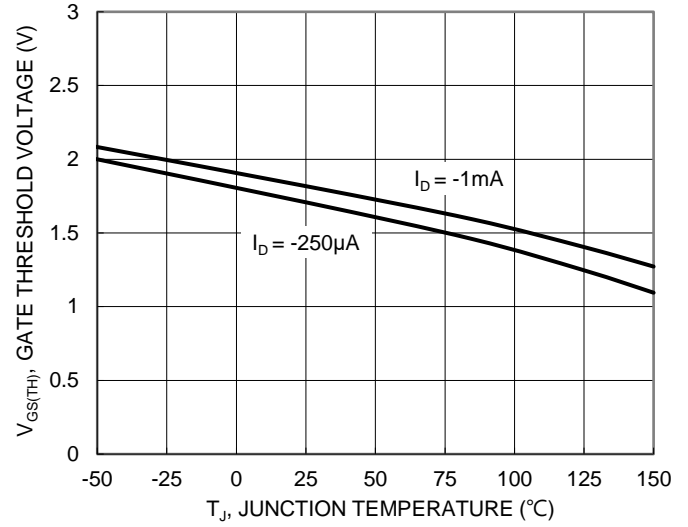


Figure 8. Gate Threshold Variation vs. Junction Temperature

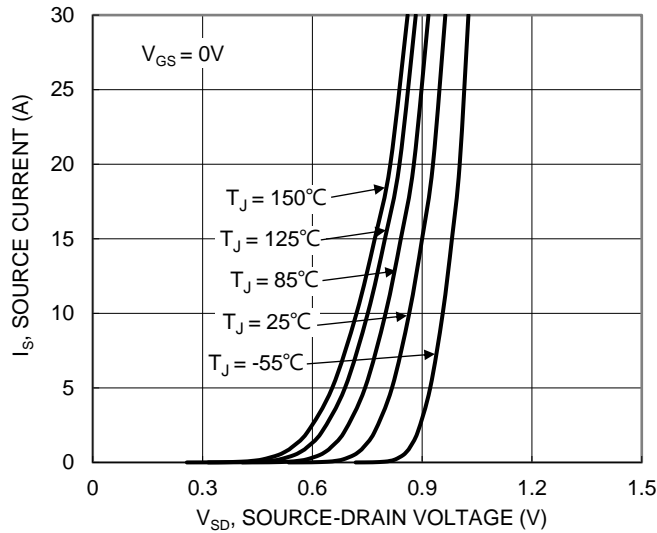


Figure 9. Diode Forward Voltage vs. Current

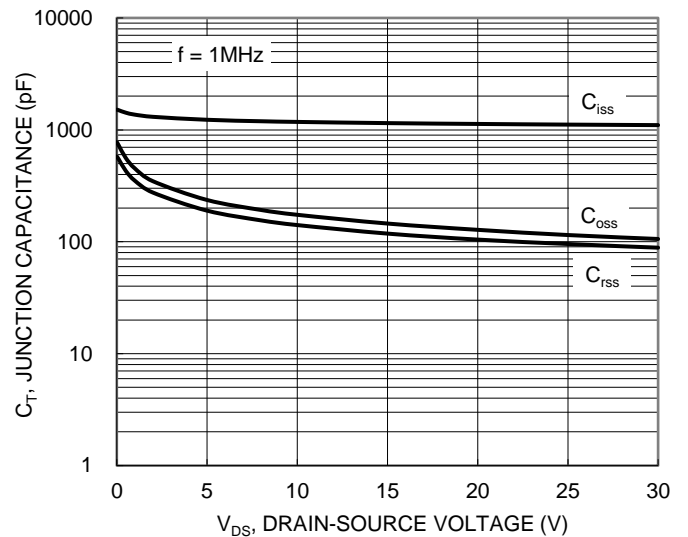


Figure 10. Typical Junction Capacitance

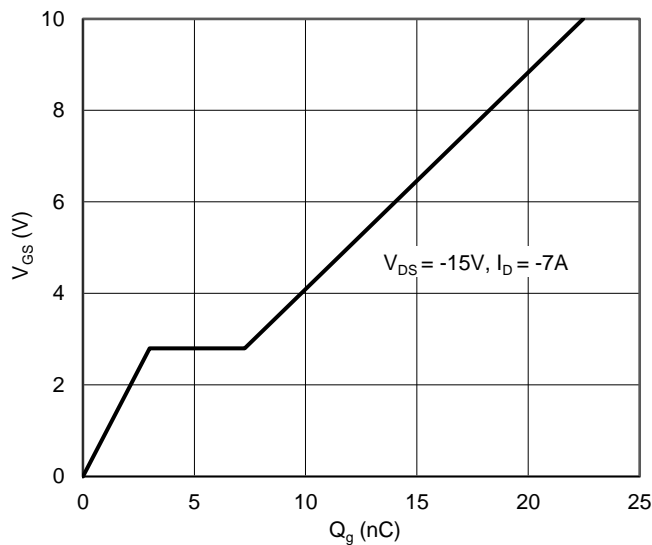


Figure 11. Gate Charge

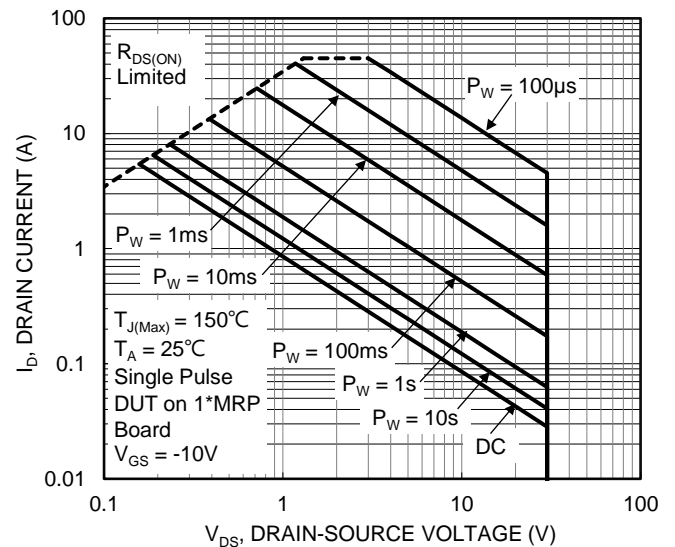


Figure 12. SOA, Safe Operation Area

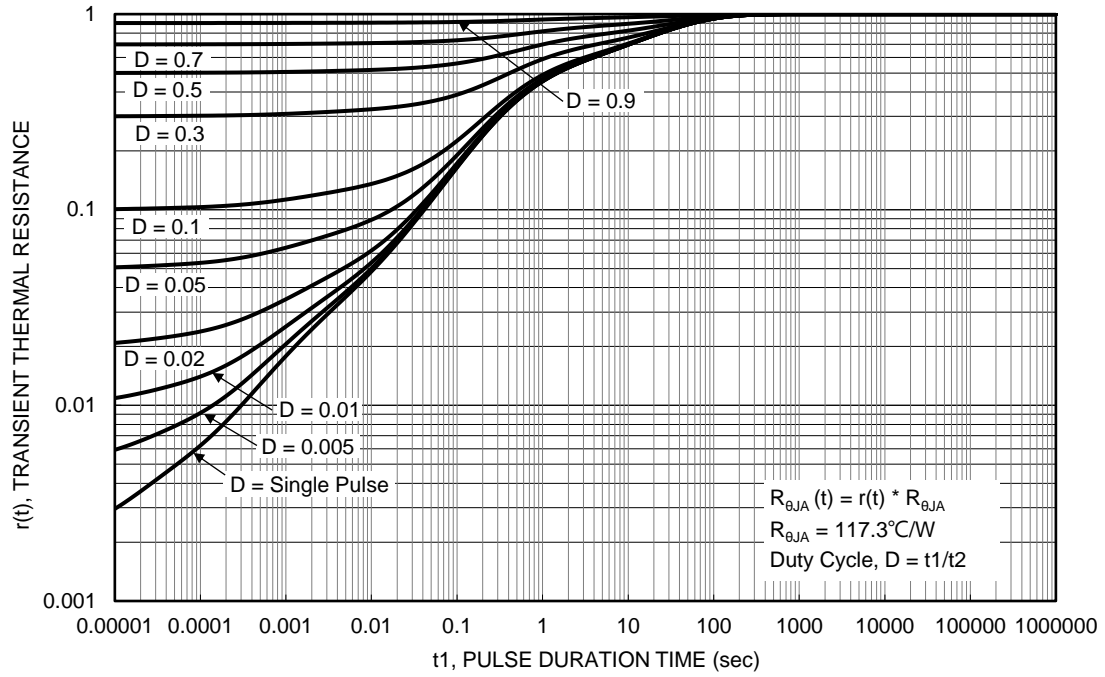


Figure 13. Transient Thermal Resistance

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

Technical drawing of a mechanical part, showing front and top views with dimensions and feature control frames.

Front View (Top):

- Overall width: A
- Overall height: C
- Feature control frame for width: $\text{ccc} \text{ } C$
- Feature control frame for height: $6 \times \text{ccc} \text{ } C$
- Seating Plane
- Dimensions $A1$ and $A3$ are indicated.

Top View (Bottom):

- Overall width: D
- Overall height: E
- Feature control frame for width: $2 \times \text{ccc} \text{ } C$
- Feature control frame for height: $\text{aaa} \text{ } C$
- Internal dimensions: $D2$, $L1$, $L(2x)$, k , $k1$, $b1$, $b(6x)$, e , $z(4x)$
- Feature control frame for width: $\text{aaa} \text{ } C$
- Feature control frame for height: $\text{bbb} \text{ } C \text{ } A \text{ } B$

U-DFN2020-6 (Type E)			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0.00	0.05	0.03
A3	—	—	0.15
b	0.25	0.35	0.30
b1	0.185	0.285	0.235
D	1.95	2.05	2.00
D2	0.85	1.05	0.95
E	1.95	2.05	2.00
E2	1.40	1.60	1.50
e	—	—	0.65
L	0.25	0.35	0.30
L1	0.82	0.92	0.87
k	—	—	0.305
k1	—	—	0.225
Z	—	—	0.20
All Dimensions in mm			

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

Dimensions	Value (in mm)
C	0.650
X	0.400
X1	0.285
X2	1.050
Y	0.500
Y1	0.920
Y2	1.600
Y3	2.300

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